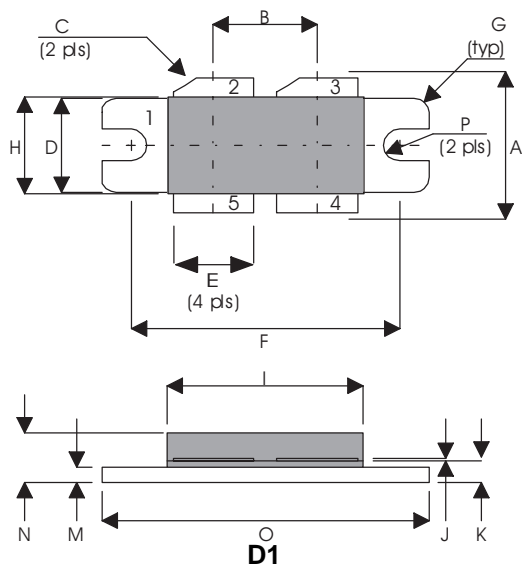


MECHANICAL DATA



PIN 1	SOURCE (COMMON)	PIN 2	DRAIN 1
PIN 3	DRAIN 2	PIN 4	GATE 2
PIN 5	GATE 1		

DIM	Millimetres	Tol.	Inches	Tol.
A	15.24	0.50	0.600	0.020
B	10.80	0.13	0.425	0.005
C	45°	5°	45°	5°
D	9.78	0.13	0.385	0.005
E	8.38	0.13	0.330	0.005
F	27.94	0.13	1.100	0.005
G	1.52R	0.13	0.060R	0.005
H	10.16	0.15	0.400	0.006
I	21.84	0.23	0.860	0.009
J	0.10	0.02	0.004	0.001
K	1.96	0.13	0.077	0.005
M	1.02	0.13	0.040	0.005
N	4.45	0.38	0.175	0.015
O	34.04	0.13	1.340	0.005
P	1.63R	0.13	0.064R	0.005

IMPROVED PERFORMANCE
GOLD METALLISED
SILICON DMOS RF FET
100W – 50V – 500MHz
PUSH-PULL

FEATURES

- SUITABLE FOR BROAD BAND APPLICATIONS
- SIMPLE BIAS CIRCUITS
- ULTRA-LOW THERMAL RESISTANCE
- BeO FREE
- LOW Crss
- HIGH GAIN – 15 dB MINIMUM

APPLICATIONS

- HF/VHF/UHF COMMUNICATIONS
from 1 MHz to 500 MHz

P_D	Power Dissipation	500W (290W -A Version)
BV_{DSS}	Drain – Source Breakdown Voltage *	125V
BV_{GSS}	Gate – Source Breakdown Voltage *	±20V
$I_{D(sat)}$	Drain Current *	9A
T_{stg}	Storage Temperature	-65 to 150°C
T_j	Maximum Operating Junction Temperature	200°C

* Per Side

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
PER SIDE					
B _V DSS	Drain-Source Breakdown Voltage	V _{GS} = 0	I _D = 100mA	125	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 50V	V _{GS} = 0		3 mA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0		1 μA
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	V _{DS} = V _{GS}	1	7 V
g _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 3A	2.4	S
TOTAL DEVICE					
G _{PS}	Common Source Power Gain	P _O = 100W		15	dB
η	Drain Efficiency	V _{DS} = 50V	I _{DQ} = 1.2A	65	%
VSWR	Load Mismatch Tolerance	f = 500MHz		20:1	—
PER SIDE					
C _{iss}	Input Capacitance	V _{DS} = 50V	V _{GS} = -5V f = 1MHz	100	pF
C _{oss}	Output Capacitance	V _{DS} = 50V	V _{GS} = 0 f = 1MHz	45	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 50V	V _{GS} = 0 f = 1MHz	1.5	pF

* Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 0.35°C / W 0.6°C / W -A Version
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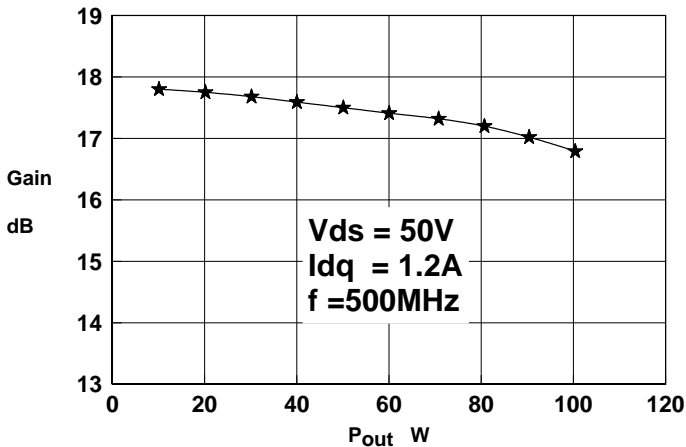


Figure 1 - Gain vs. Power Output.

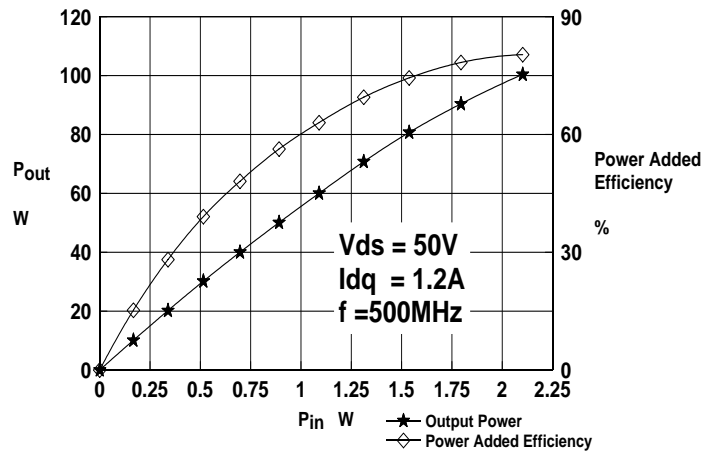


Figure 2 - Power Output & Efficiency vs. Power Input.

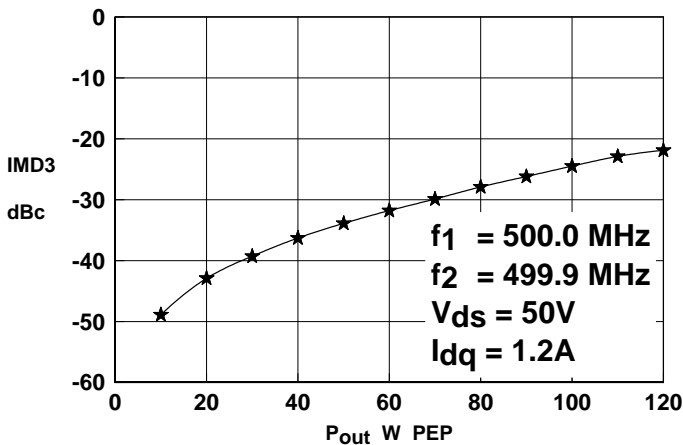


Figure 3 - IMD vs. Output Power.

DMD5012

OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	Z_S Ω	Z_L Ω
500	$1.6 + j2.3$	$3.5 + j2.1$

N.B. Impedances measured terminal to terminal

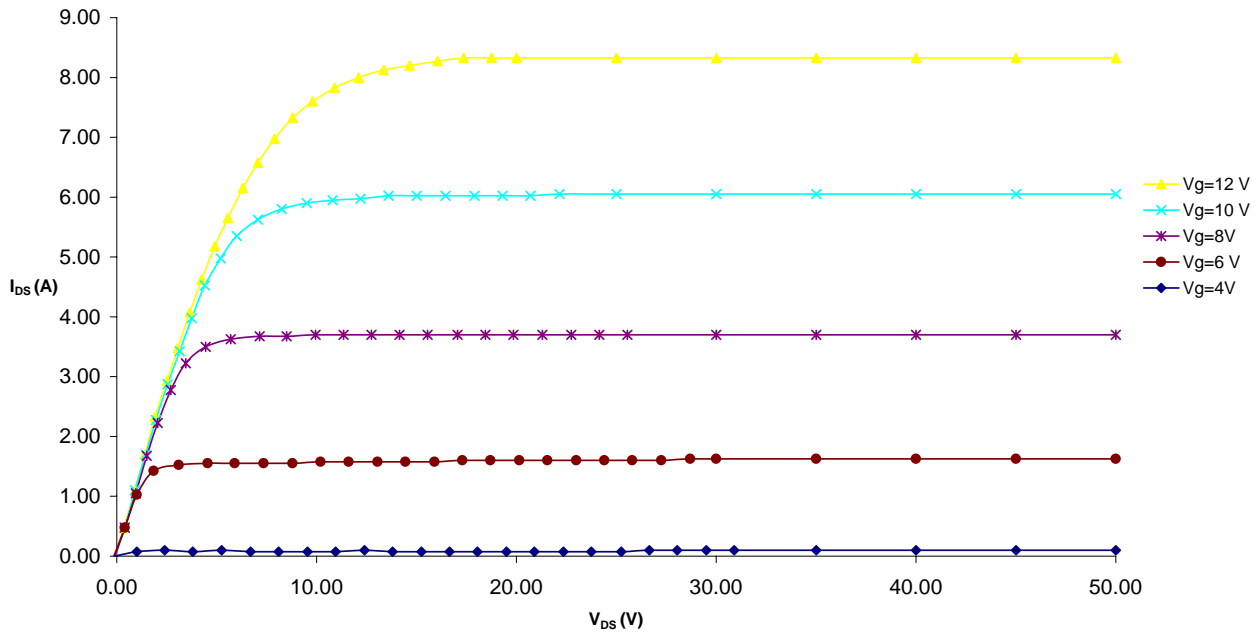


Figure 4 – Typical IV Characteristics.

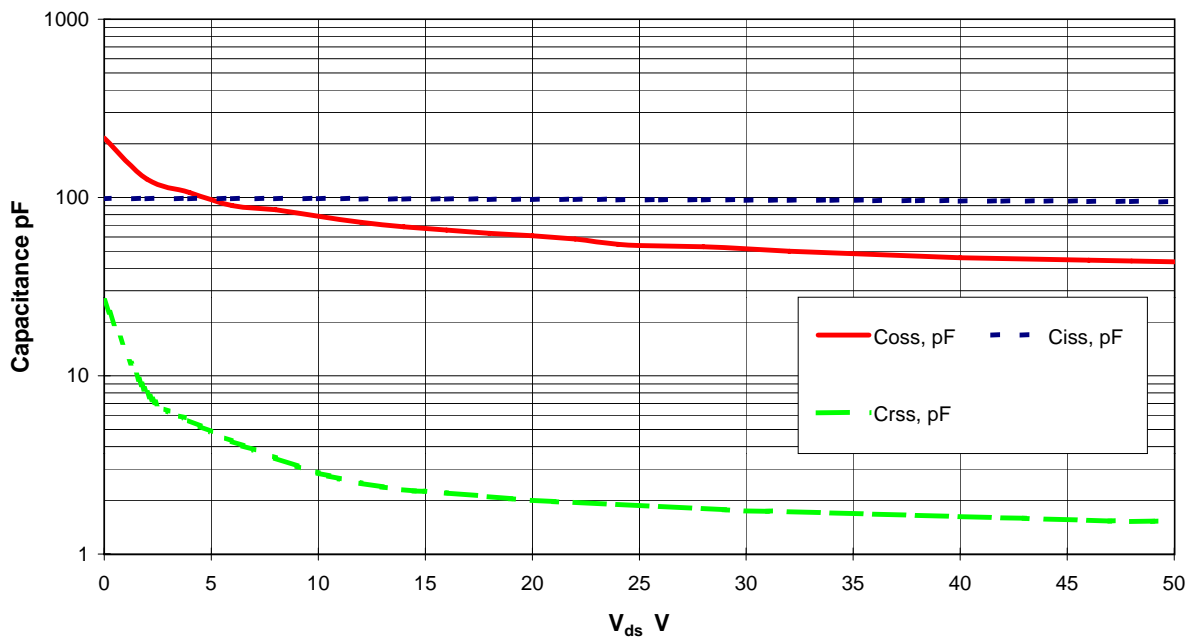
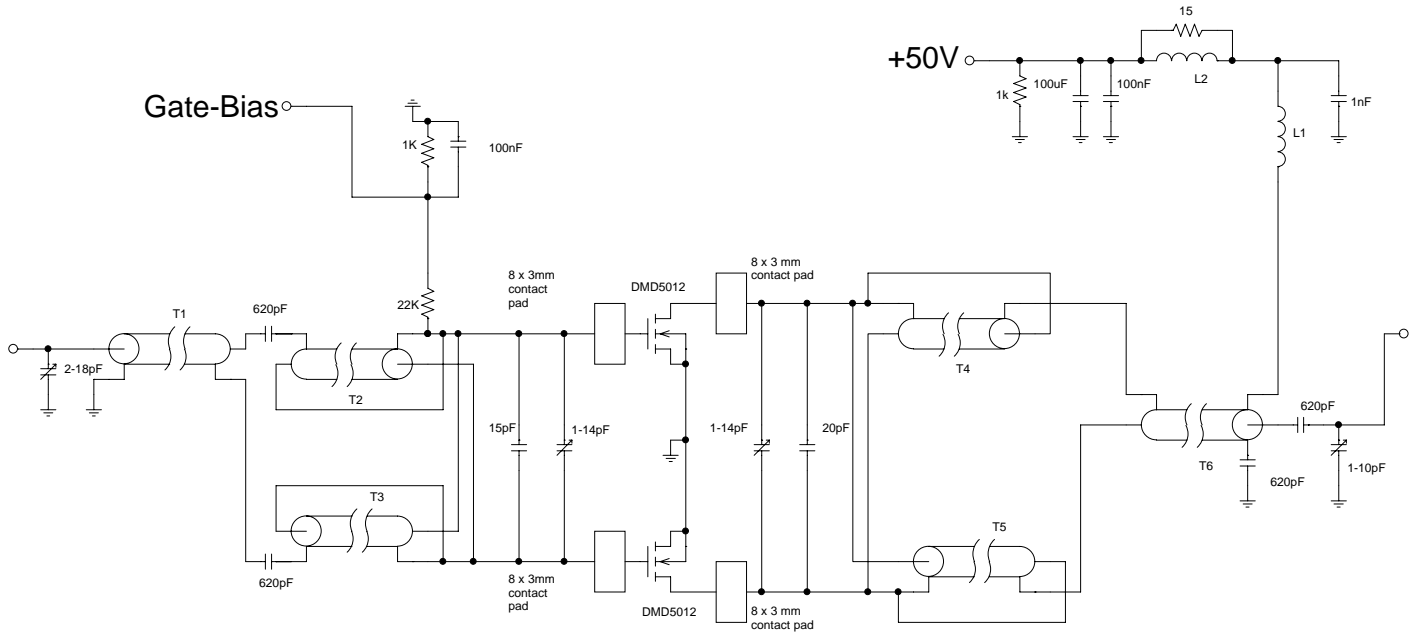


Figure 5 – Typical CV Characteristics.

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DMD5012 500MHz TEST FIXTURE

T1,6	65mm	50 Ohm UT85 semi-rigid coax
T2,3,4,5	75mm	15 Ohm UT85-15 semi-rigid coax
L1	6 turns	21 swg enamelled copper wire, 3mm i.d.
L2	8.5 turns	19 swg enamelled copper wire on Fair-Rite FT82-43 core